

Paramagnetic Mott-Hubbard metal-insulator transition in $d = \infty$

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Introduction

QMC solution of DMFT equations

Results: Coexistence region

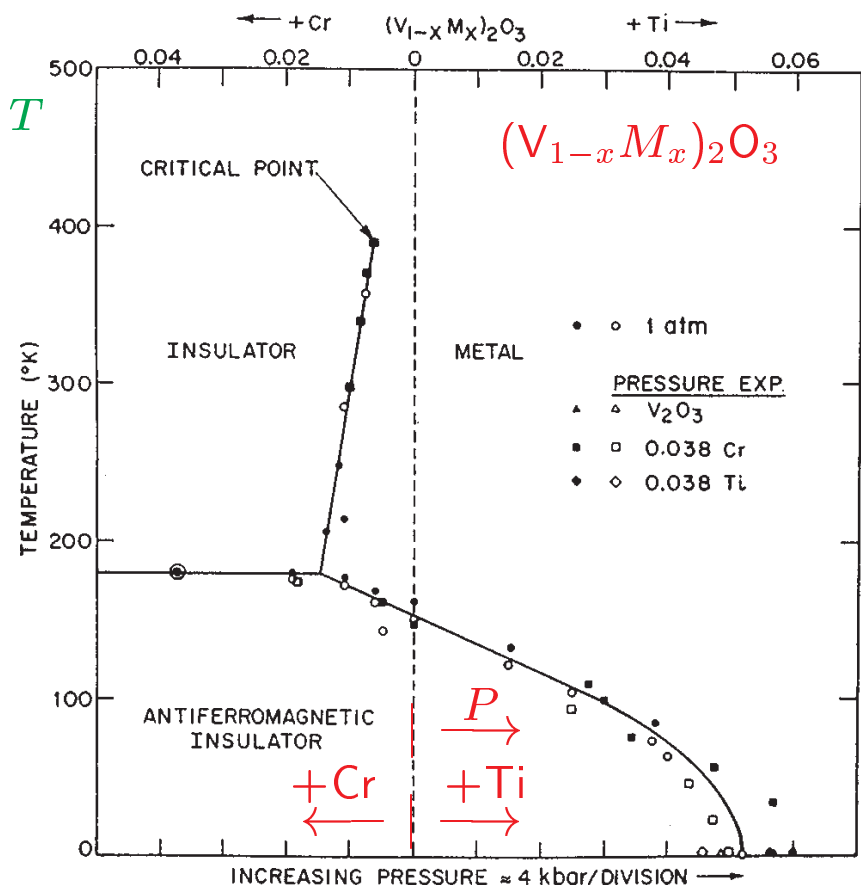
Comparing free energies

Low temperatures

Results: Full paramagnetic phase diagram

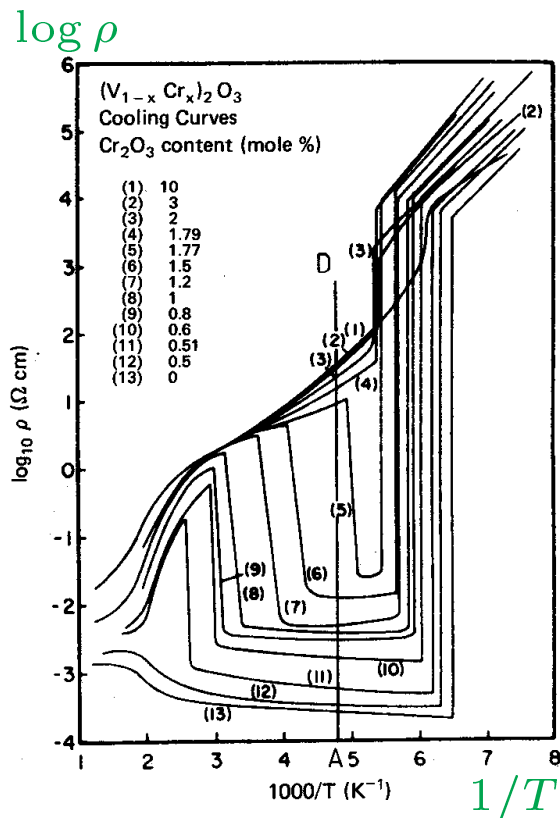
Conclusions

Introduction



McWhan et al, 1971

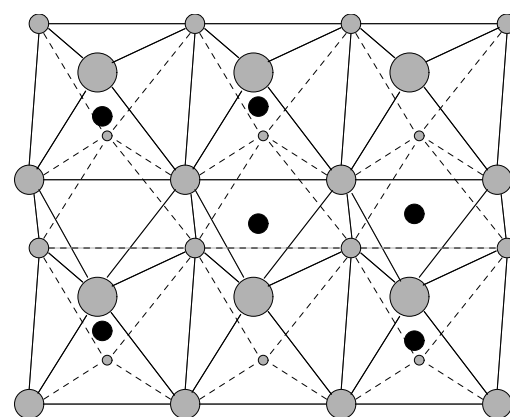
$\leftarrow U/W$



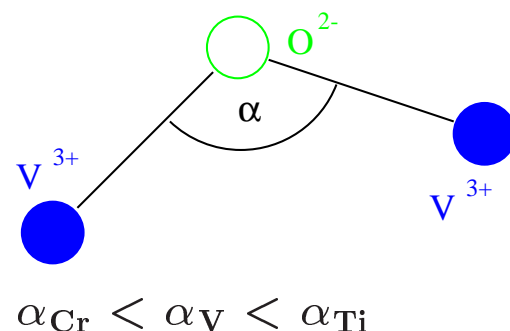
Kawamoto et al, 1980

Motivation: V_2O_3

- MIT without LRO
- drop in resistivity ρ by factor 10^3
- shift in lattice parameters
- Corundum structure:
 - hcp O^{2-} lattice
 - V^{3+} fill 2/3 of octahedral vacancies
- doping with Ti, Cr:
 - (nearly) isovalent
 - distorts lattice \rightarrow changes overlap
 - drives MIT (like pressure)



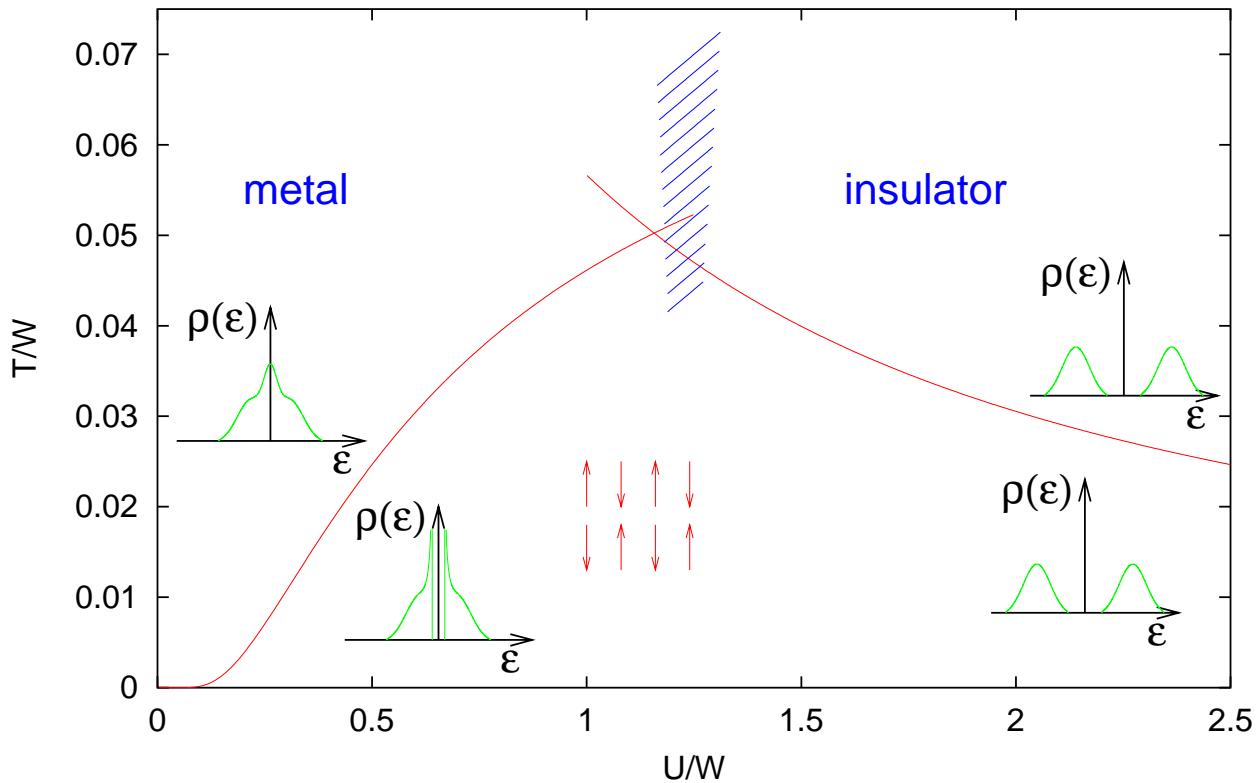
Corundum structure



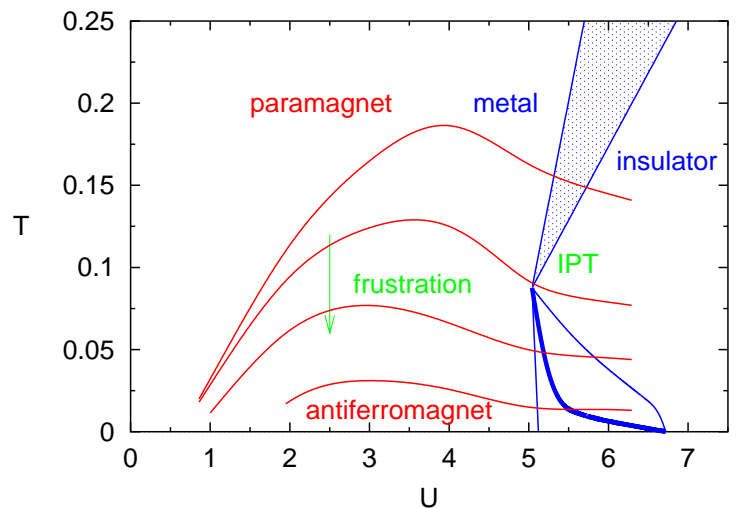
Paramagnetic, bandwidth-controlled metal-insulator transition in V_2O_3

half-filled one-band Hubbard model

$$\hat{H} = -t \sum_{\langle ij \rangle \sigma} \left(\hat{c}_{i\sigma}^\dagger \hat{c}_{j\sigma} + \hat{c}_{j\sigma}^\dagger \hat{c}_{i\sigma} \right) + U \sum_i \hat{n}_{i\uparrow} \hat{n}_{i\downarrow}$$



- here: no MIT, but crossover
- antiferromagnetism is understood at weak and strong coupling
- AF frustrated in many materials
- nonperturbative approach needed
- thermodynamic limit important



Aim: full phase diagram for

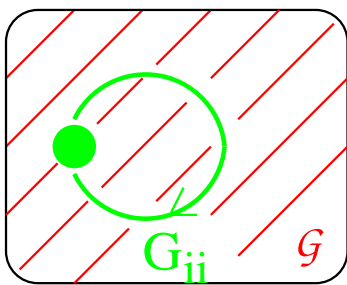
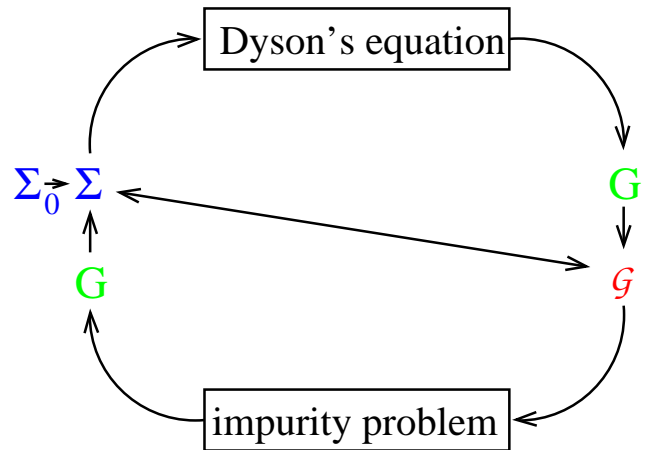
- 1-band Hubbard model at half filling
- Dynamical Mean-Field Theory (DMFT)
- no AF order (full frustration)
- semielliptic Bethe DOS ($W = 4$)

Self-consistent solution of DMFT equations

$$G_n = \int d\epsilon \frac{\rho(\epsilon)}{i\omega_n - \epsilon - \Sigma_n}$$

$$G_n = - \langle \Psi_n \Psi_n^* \rangle \mathcal{G}_n$$

$$\mathcal{G}_n^{-1} = G_n^{-1} + \Sigma_n$$



QMC solution of impurity problem:

- discretization $\Delta\tau$ of imaginary time
- Hubbard-Stratonovich trafo
- MC sampling over auxiliary Ising field

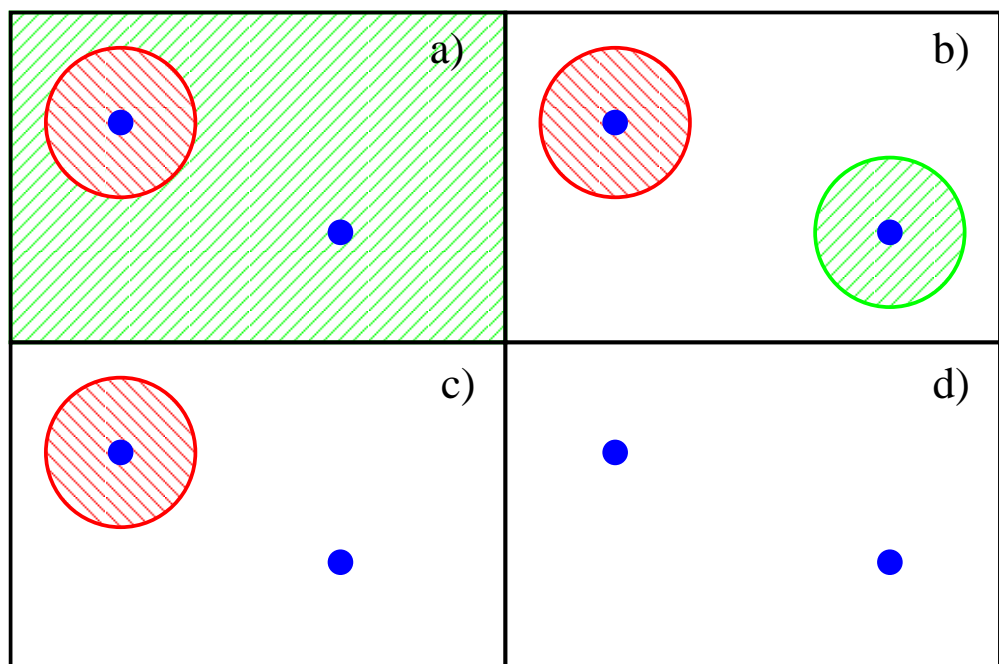
abstract view: solution of fixed point problem by iteration

iteration scheme not determined by lattice problem

instability of fixed point cannot be proven within iteration scheme

but: seems to work in practice!

scheme:
convergence in
2-fixpoint
problem
(2-dimensional
example)



Results: crossover and coexistence regions

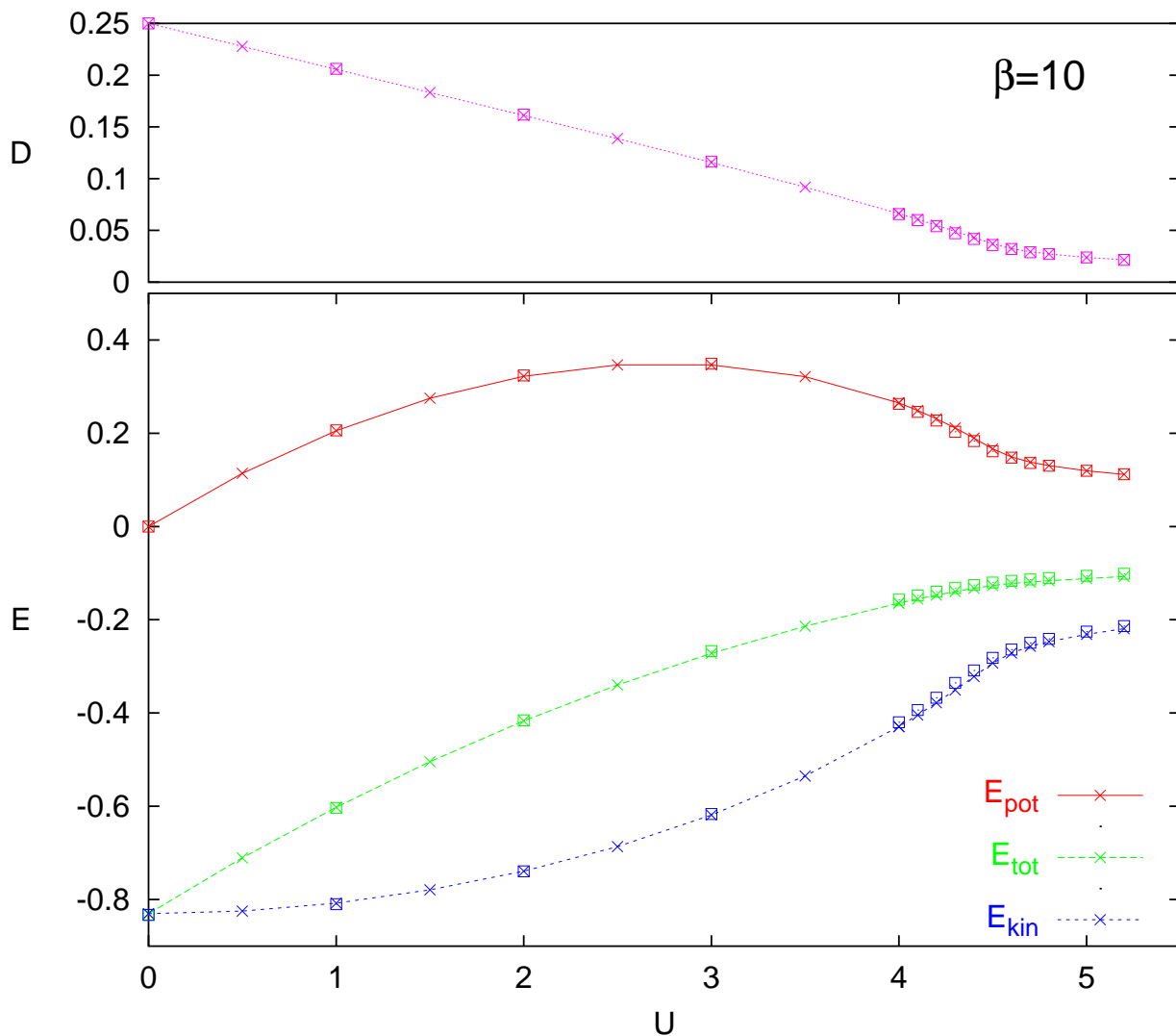
double occupancy D , total energy per lattice site $E = E_{kin} + UD$

$$D = \frac{1}{\beta} \int_0^\beta d\tau (1 + G(\tau))^2$$

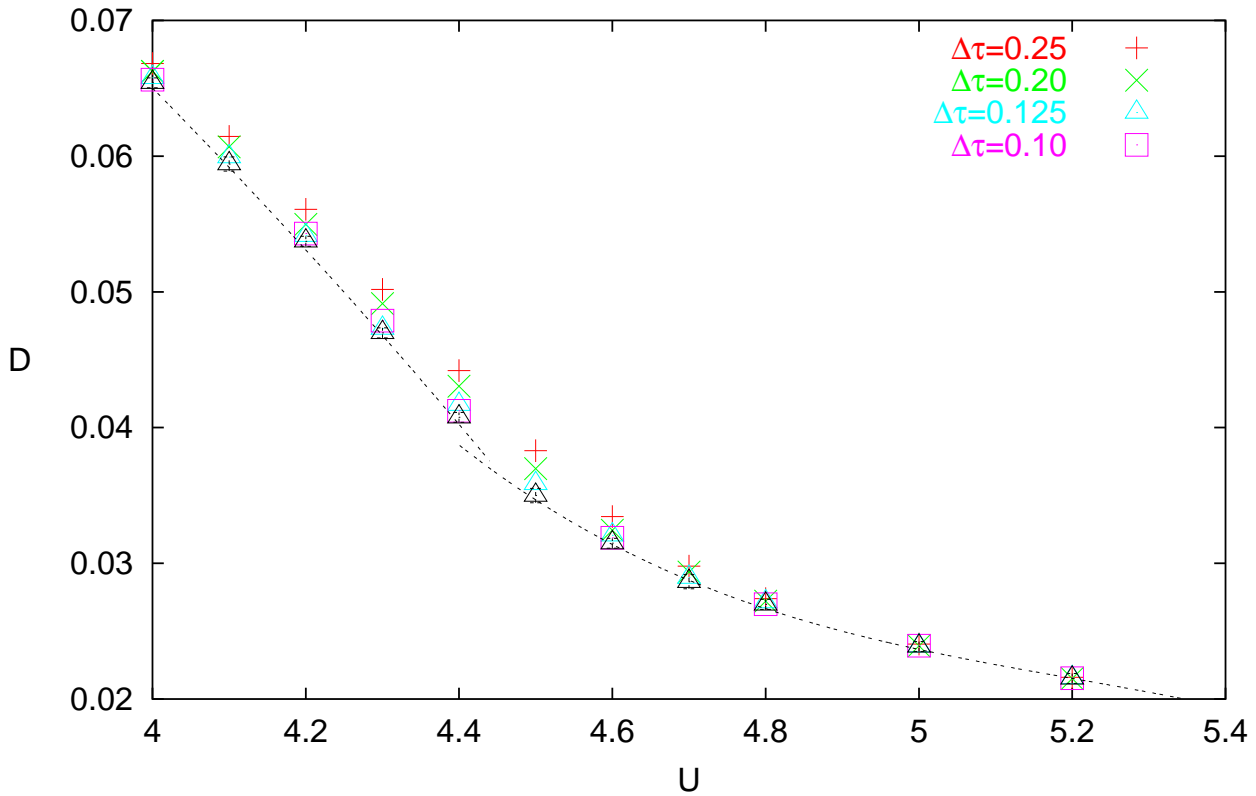
$$E_{kin} = \lim_{\eta \rightarrow 0^+} 2T \sum_{n=-\infty}^{\infty} \int_{-\infty}^{\infty} d\epsilon \frac{e^{i\omega_n \eta} \epsilon \rho(\epsilon) \cdot 1}{i\omega_n - \epsilon - \Sigma(i\omega_n)}$$

$$= 2 \int_{-\infty}^{\infty} d\epsilon \frac{\epsilon \rho(\epsilon)}{e^{\beta\epsilon} + 1}$$

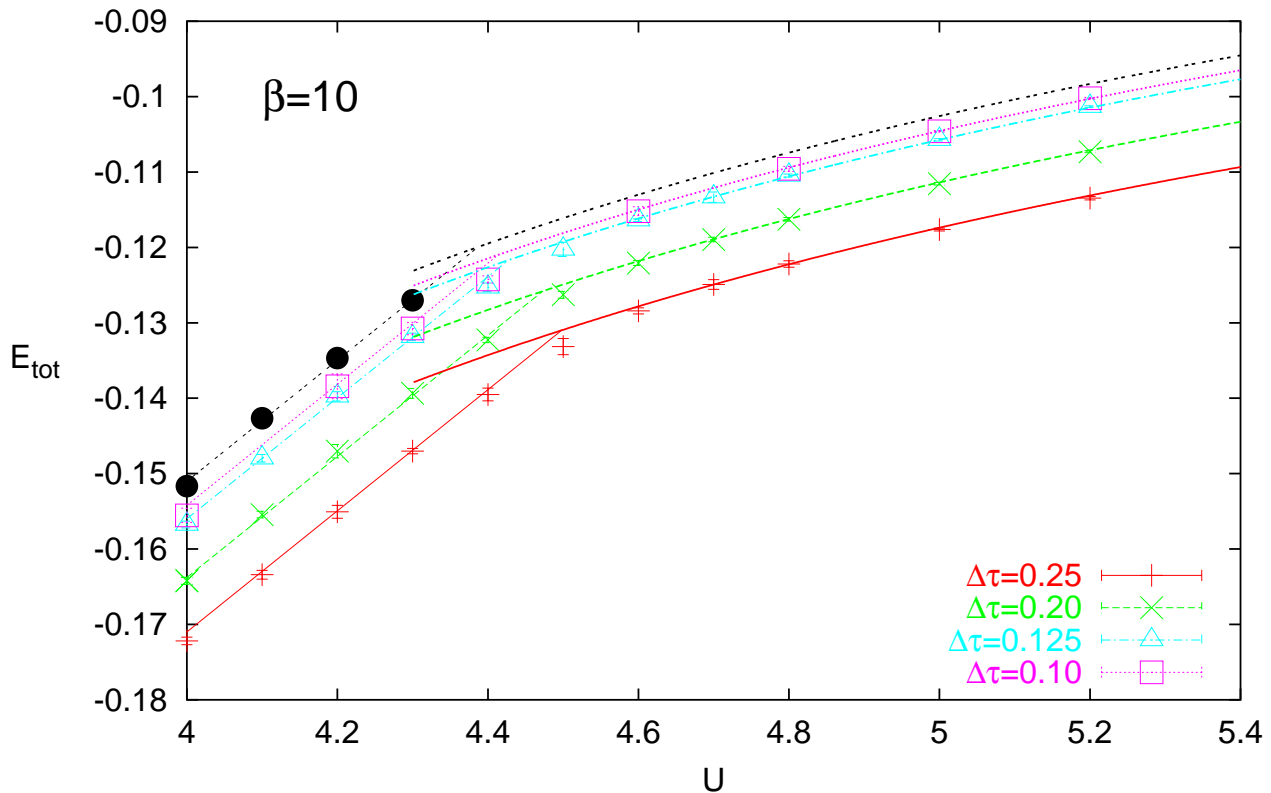
$$+ 2T \sum_{n=-L/2+1}^{L/2} \int_{-\infty}^{\infty} d\epsilon \epsilon \rho(\epsilon) \left(G_\epsilon(i\omega_n) - G_\epsilon^0(i\omega_n) \right)$$



$\beta = 10$: smooth crossover from metal to insulator

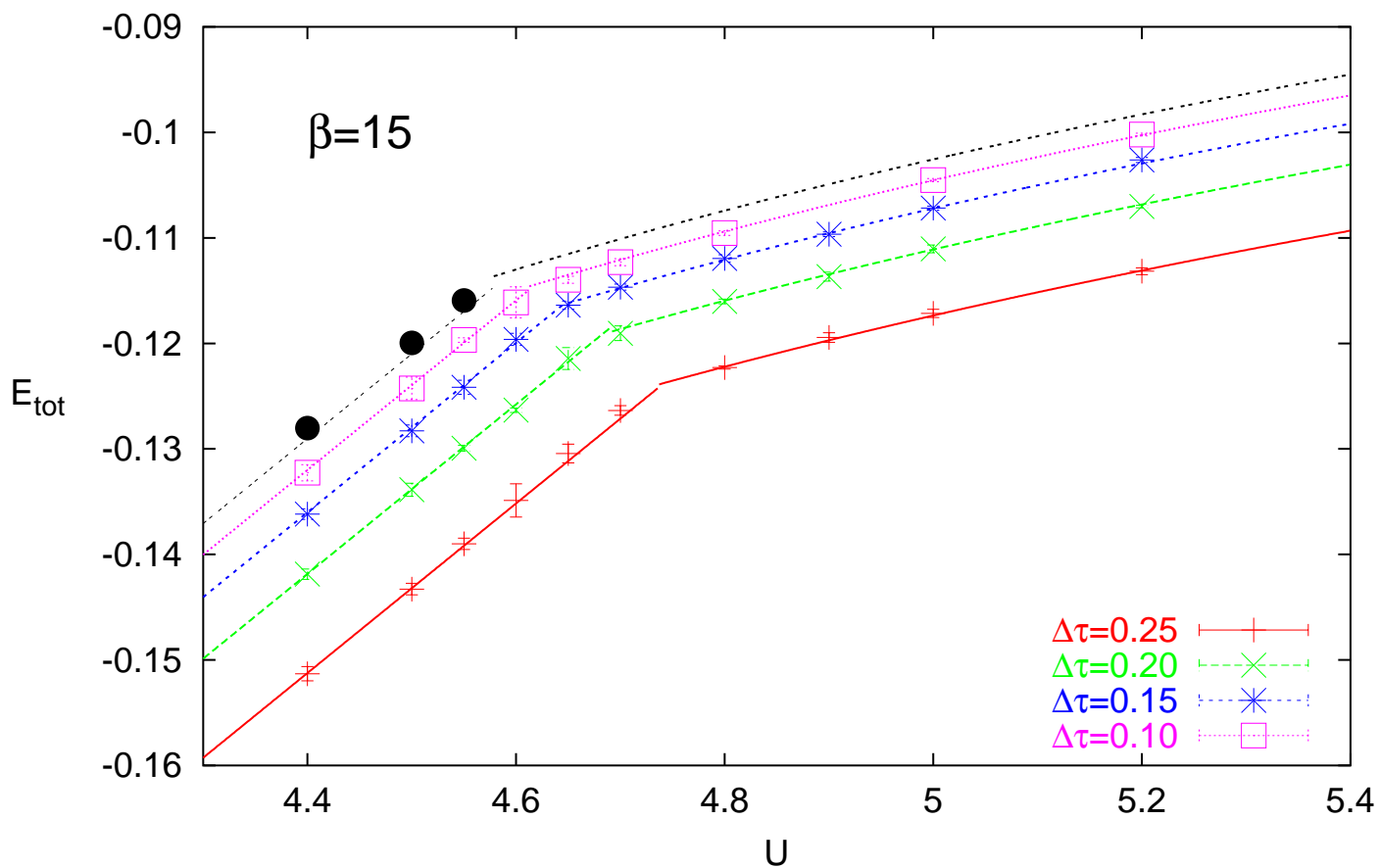
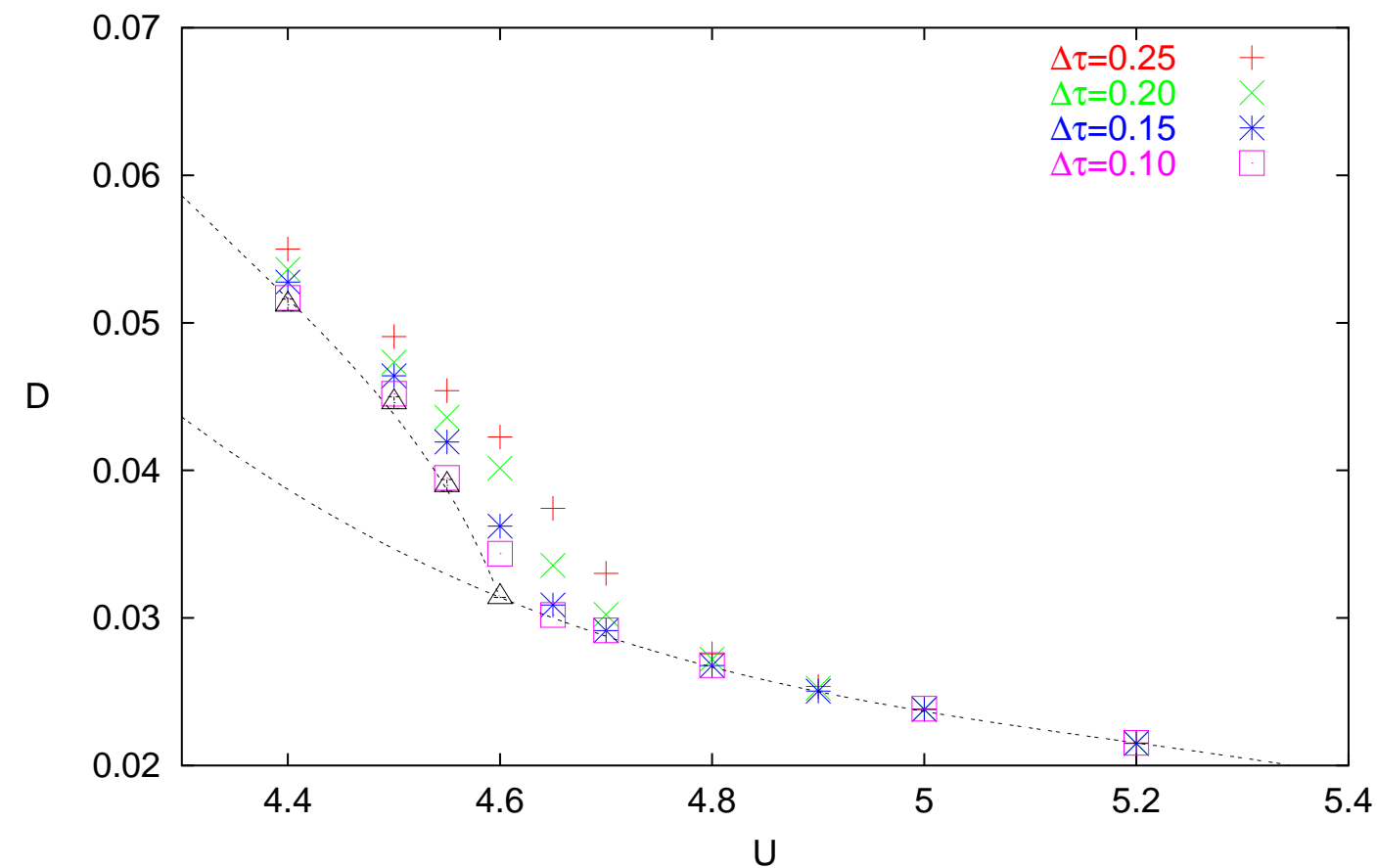


$\Delta\tau$ dependence: large at MIT , small below, vanishing above relatively strong curvature



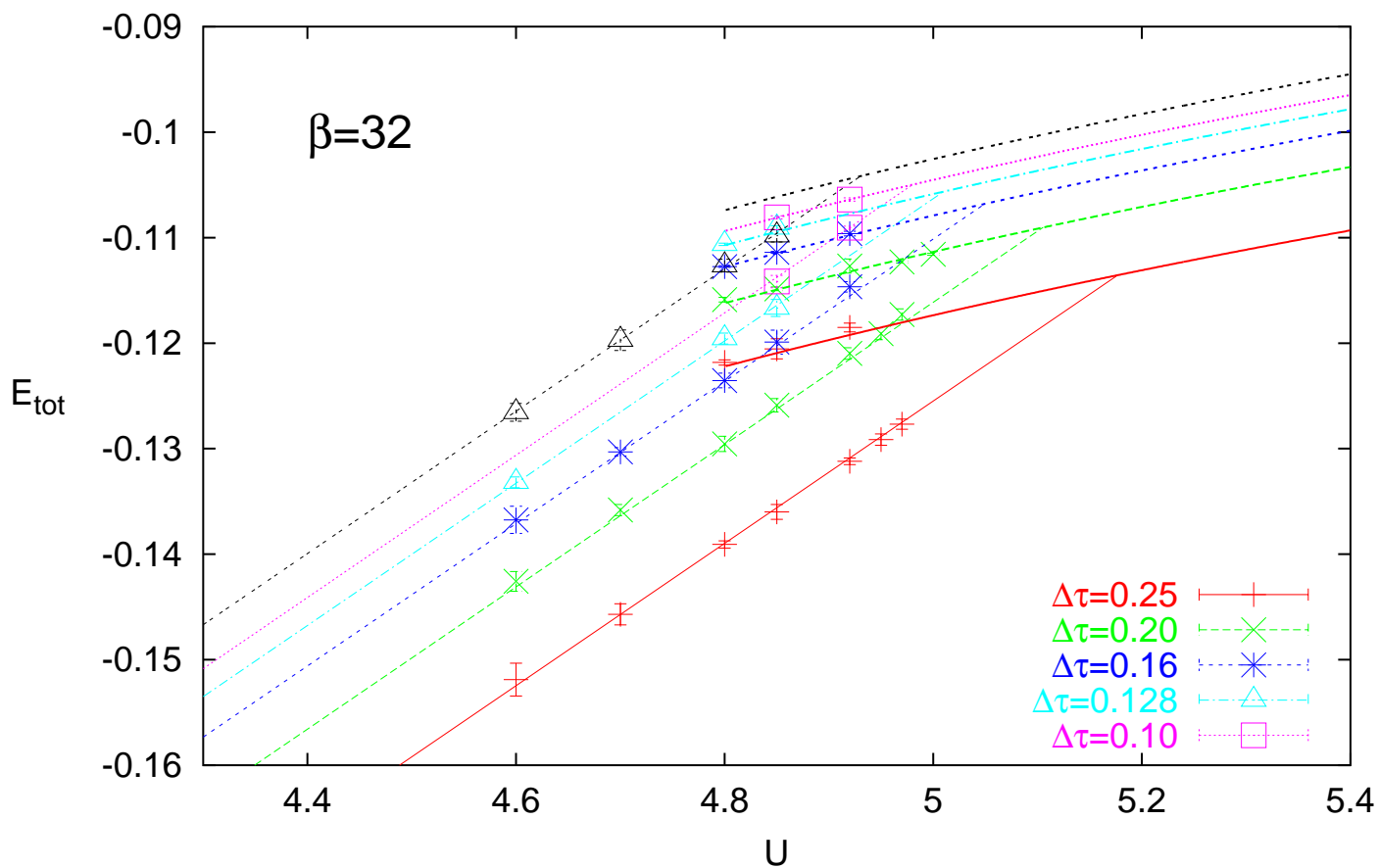
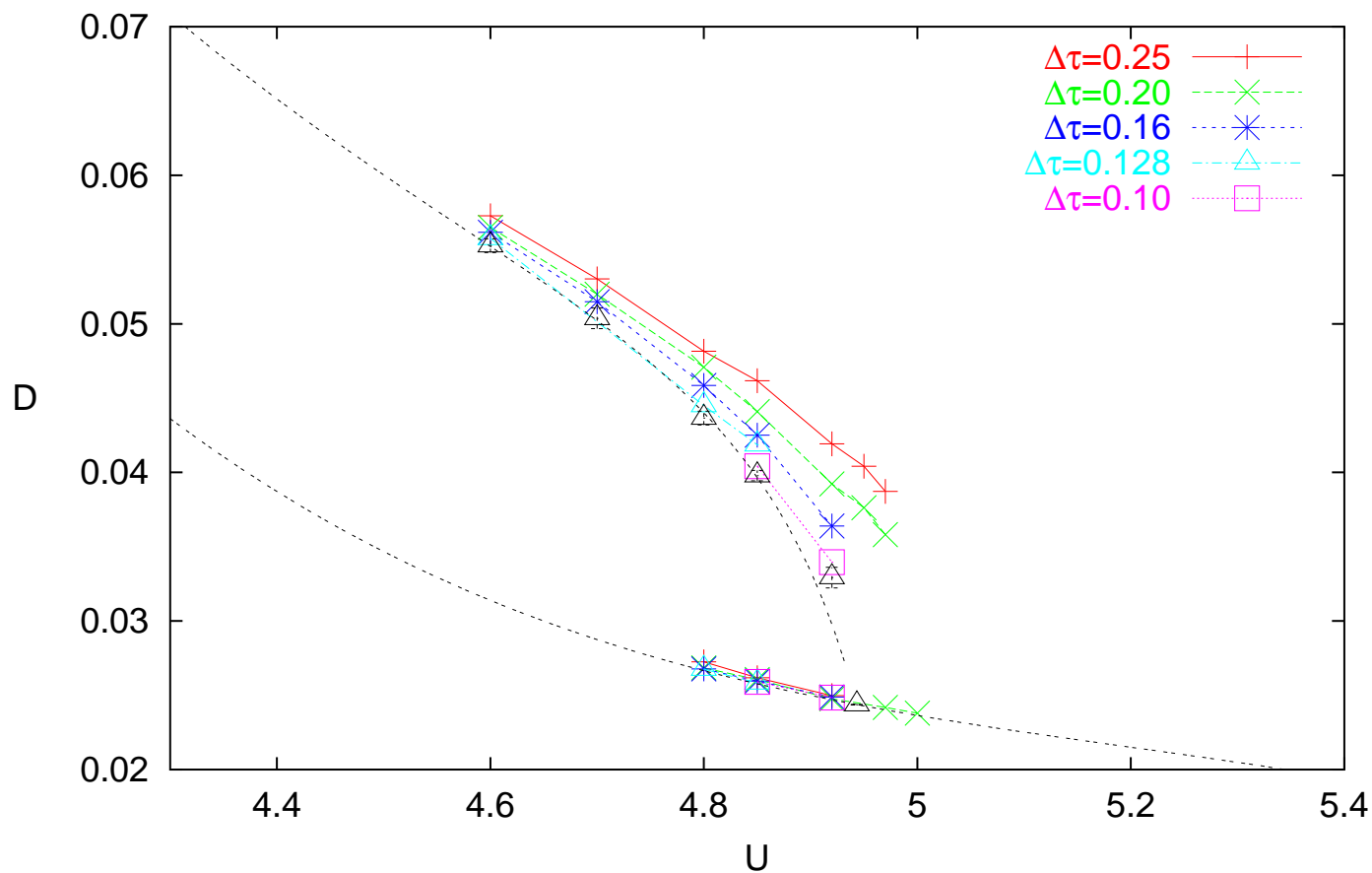
$\Delta\tau$ dependence: very regular

$\beta = 15$: sharp transition from metal to insulator, no hysteresis

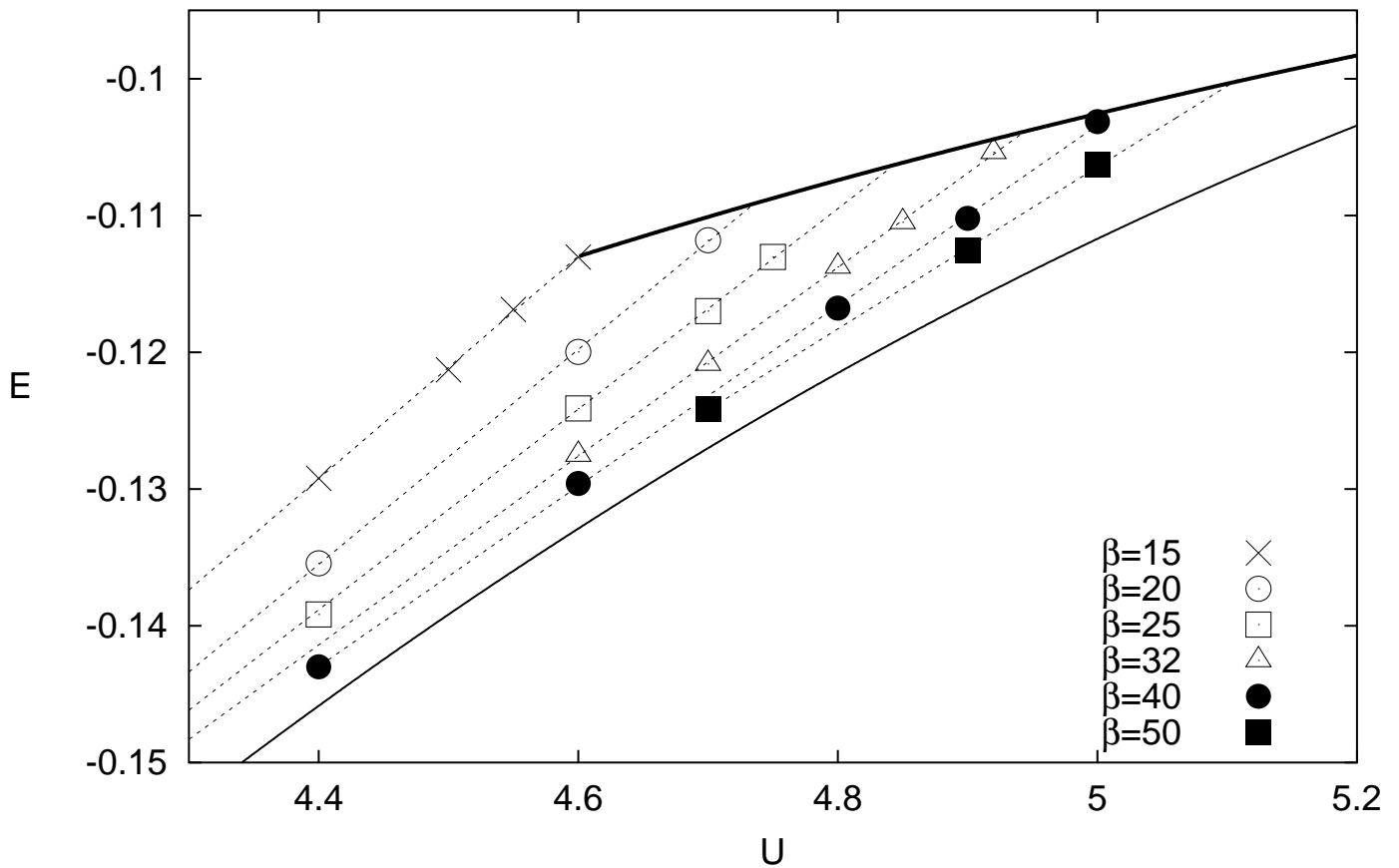
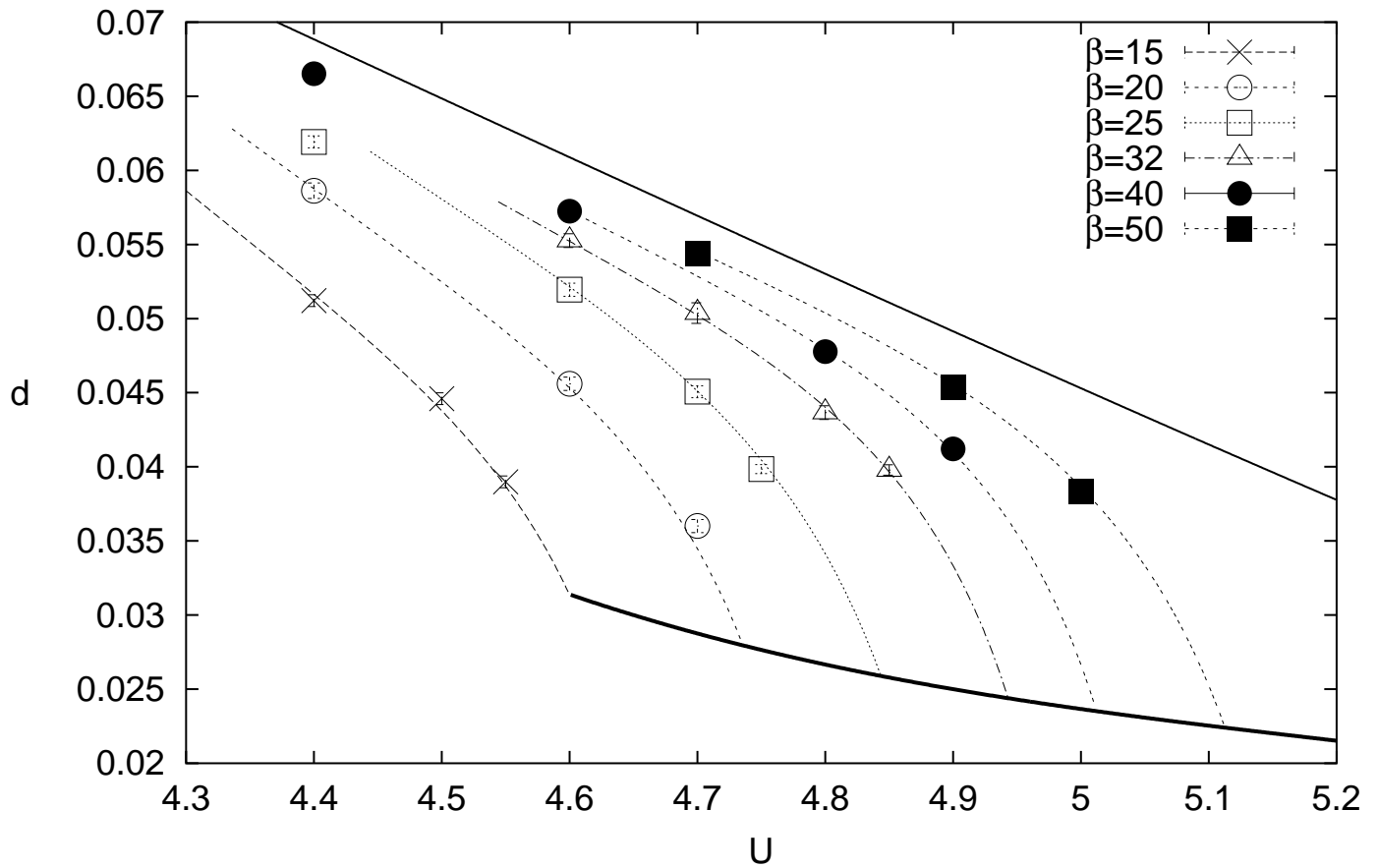


U_c substantially shifts for $\Delta\tau \rightarrow 0$

$\beta = 32$: coexistence of metallic and insulating solutions

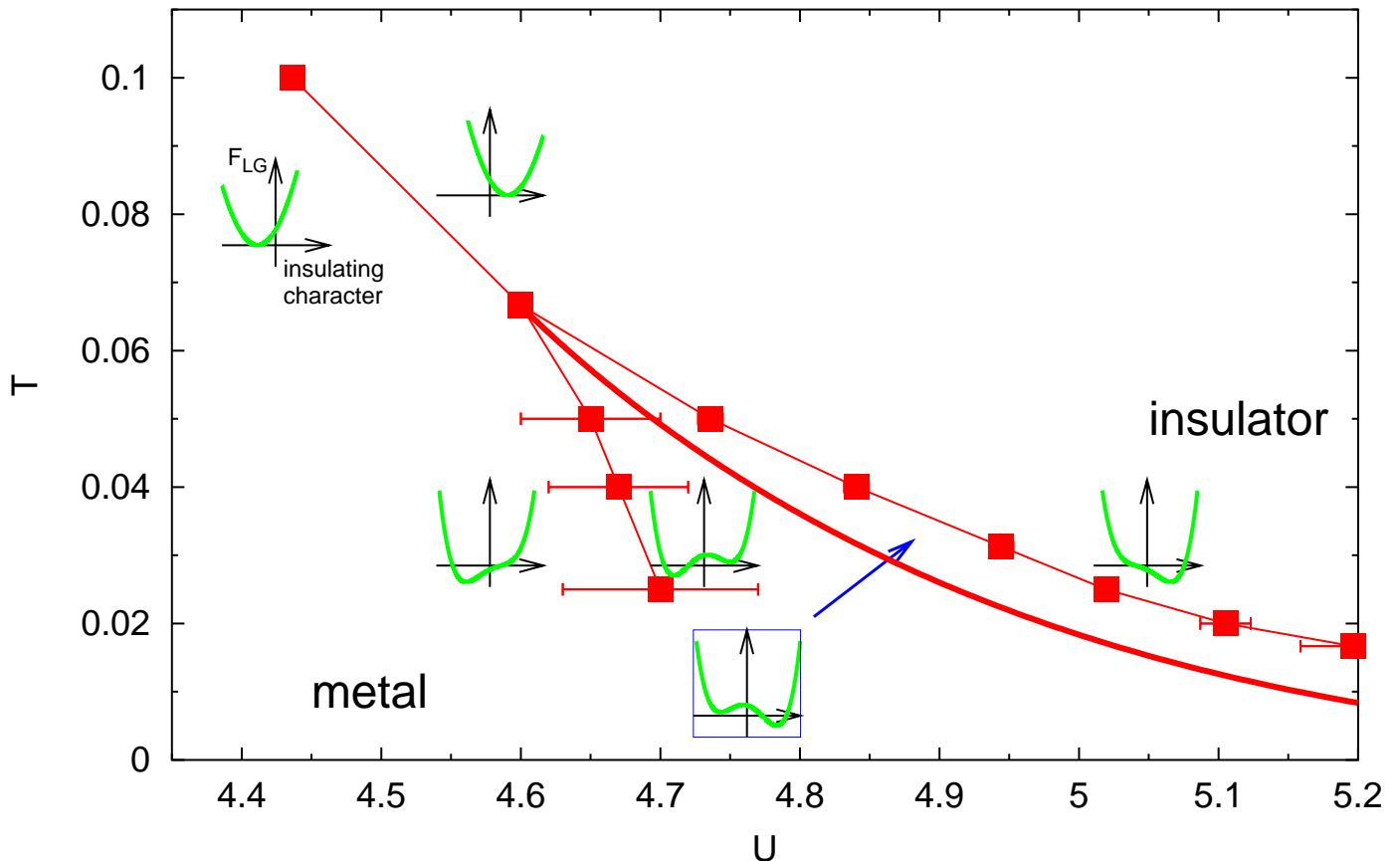


D and E versus temperature (plus extrapolation $T \rightarrow 0$)



no (significant) T -dependence of D , E in insulating phase

Phase diagram: coexistence region



Comparing free energies

$F(U, T)$ cannot be directly computed from QMC, NRG
but differential known:

$$d(\beta F_{m/i}(\beta, U)) = E_{m/i}(\beta, U)d\beta + \beta D_{m/i}(\beta, U)dU$$

Naive solution: $F(\beta, U) = F(\beta_0, U_0) + \int_{\beta_0, U_0}^{\beta, U} d(\beta' F_{m/i}(\beta', U'))$

Problem: $F_{m/i}(\beta_0, U_0)$ must be known

1st improvement: compute $\Delta F(\beta, U) := F_m(\beta, U) - F_i(\beta, U)$

$$\Delta F(\beta, U) = \int_{\beta_0, U_0}^{\beta, U} d(\beta' F_{m/i}(\beta', U'))$$

Problem: different paths of integration introduce different systematic errors for metal and insulator

local criterion:

$$d(\beta\Delta F(\beta, U)) = \Delta E(\beta, U)d\beta + \beta\Delta D(\beta, U)dU$$

at (smooth) transition line:

$$\Delta F(\beta, U)|_{U=U_c(\beta)} = 0; \quad d(\beta\Delta F(\beta, U))|_{U=U_c(\beta)} = 0$$

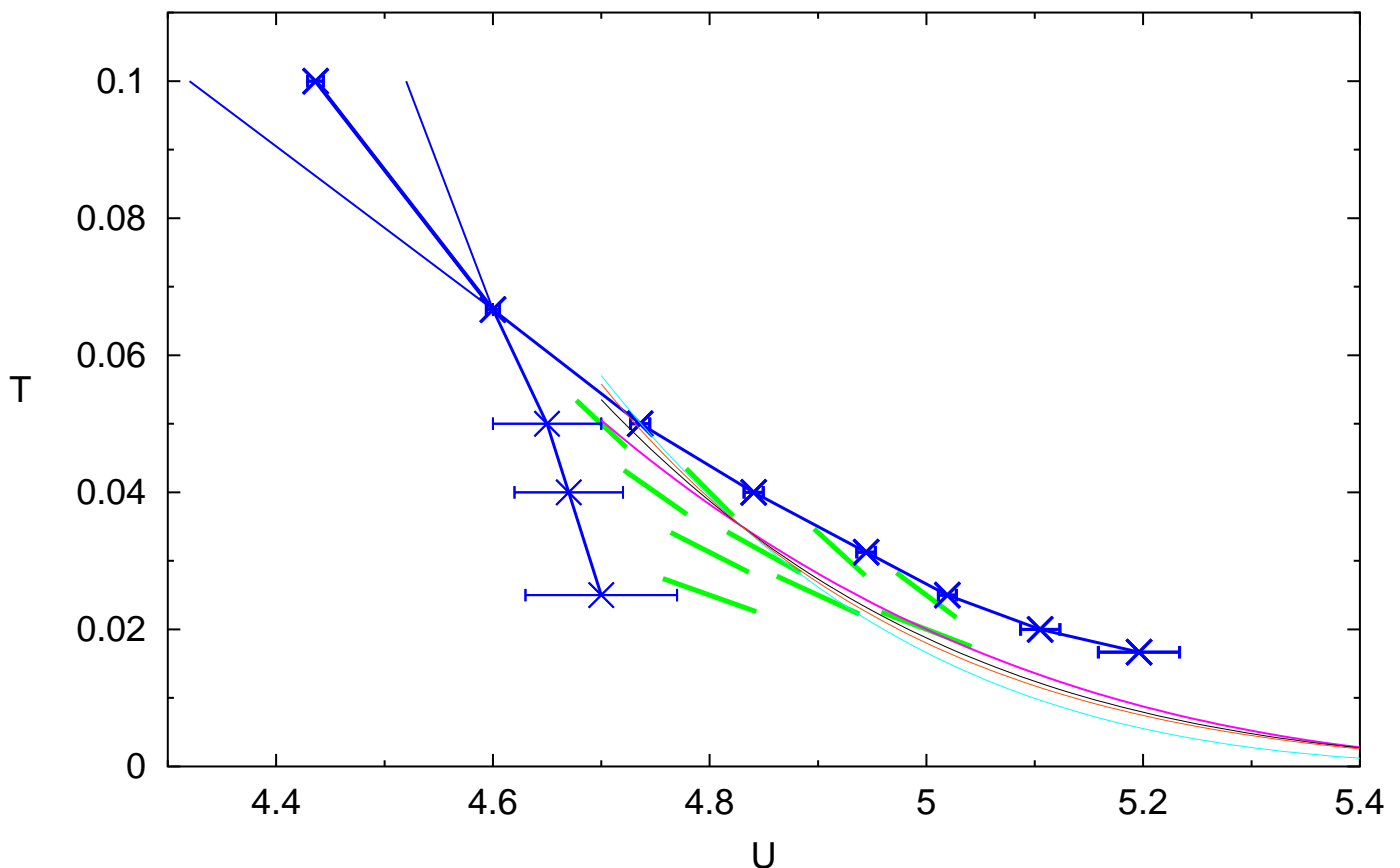
→ Clausius-Clapeyron equation:

$$\frac{dU_c(T)}{dT} = f(T, U_c(T))$$

$$f(T, U) := \frac{\Delta E(T, U)}{T\Delta D(T, U)} \Big|_{U=U_c(T)}.$$

Since $U_c(T^*) = U^*$, we can integrate for the solution,

$$U_c(T) = U^* + \int_{T^*}^T dT' f(T', U_c(T')); \quad T < T^*.$$



note: $f(T, U)$ can be linearized in U

$$f(T, U) \approx \tilde{f}(T)(A + BU); \quad \text{fit parameters } A, B$$

supplement QMC results with low- T information:

entropy of insulator (almost) independent of U

$$E_i(U, T) = E_i^0(U); \quad S_i(U, T) = S_0. \quad (1)$$

Fermi liquid properties in metal

$$E_m(U, T) = E_m^0(U) + \frac{1}{2}\gamma(U)T^2; \quad S_i(U, T) = \gamma(U)T \quad (2)$$

zero-temperature information ($U_c^0 := U_c(T=0) = U_{c2}(T=0)$)

$$E_i^0(U) - E_m^0(U) = \frac{a}{2}(U - U_c^0)^2; \quad \gamma(U) = \frac{\gamma_0}{U_c^0 - U}. \quad (3)$$

Equate free energies,

$$0 = \Delta F(U_c, T) = \frac{a}{2}(U - U_c^0)^2 + \frac{1}{2}\gamma(U)T^2 - TS_0, \quad (4)$$

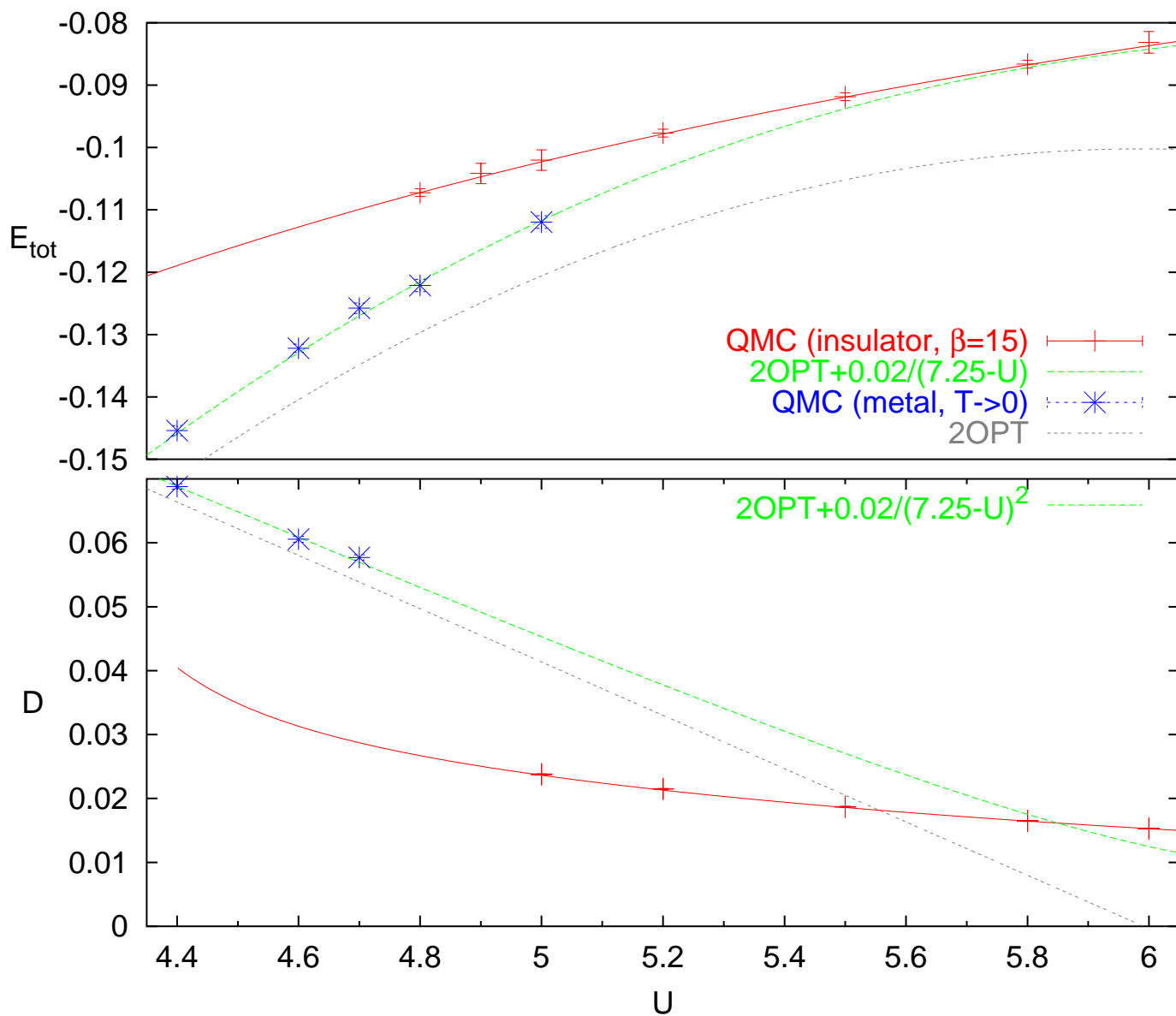
to obtain the low-temperature solution,

$$U_c(T) = U_c^0 - \sqrt{\frac{2S_0T}{a}} + \mathcal{O}(T) \quad (5)$$

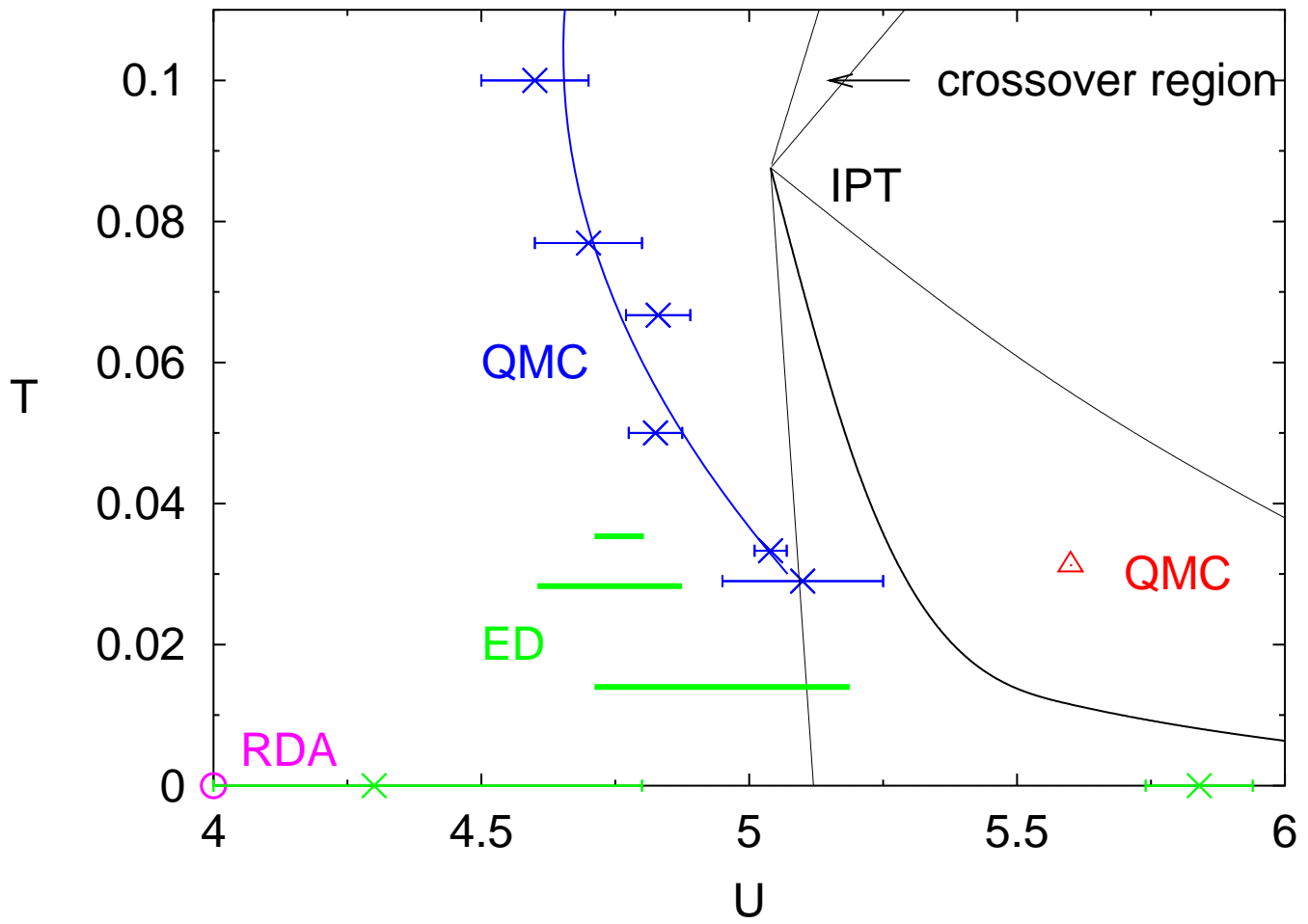
→ fitting Ansatz

$$\tilde{f}(T) = CT^{-1/2} + D + ET^{1/2}; \quad C \approx -\sqrt{\frac{S_0}{2a}}$$

determination of $T = 0$ parameters from second order PT + QMC



Status of phase diagram in spring 1999



Georges et al. (1996)

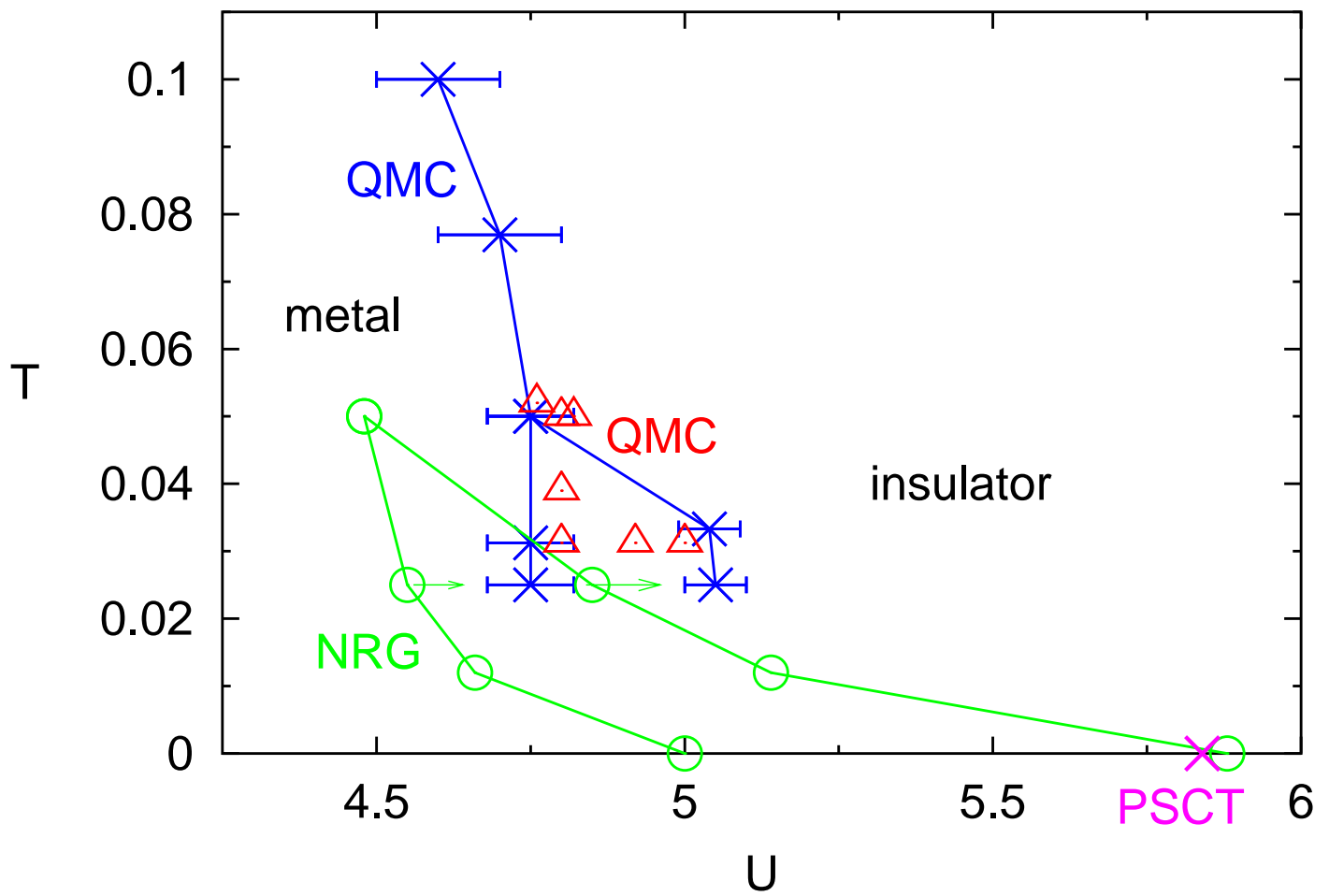
Rozenberg, Kotliar, and Zhang (1994)

Noack and Gebhard (1999)

Georges et al (1996); Hofstetter

Schlipf et al (1999)

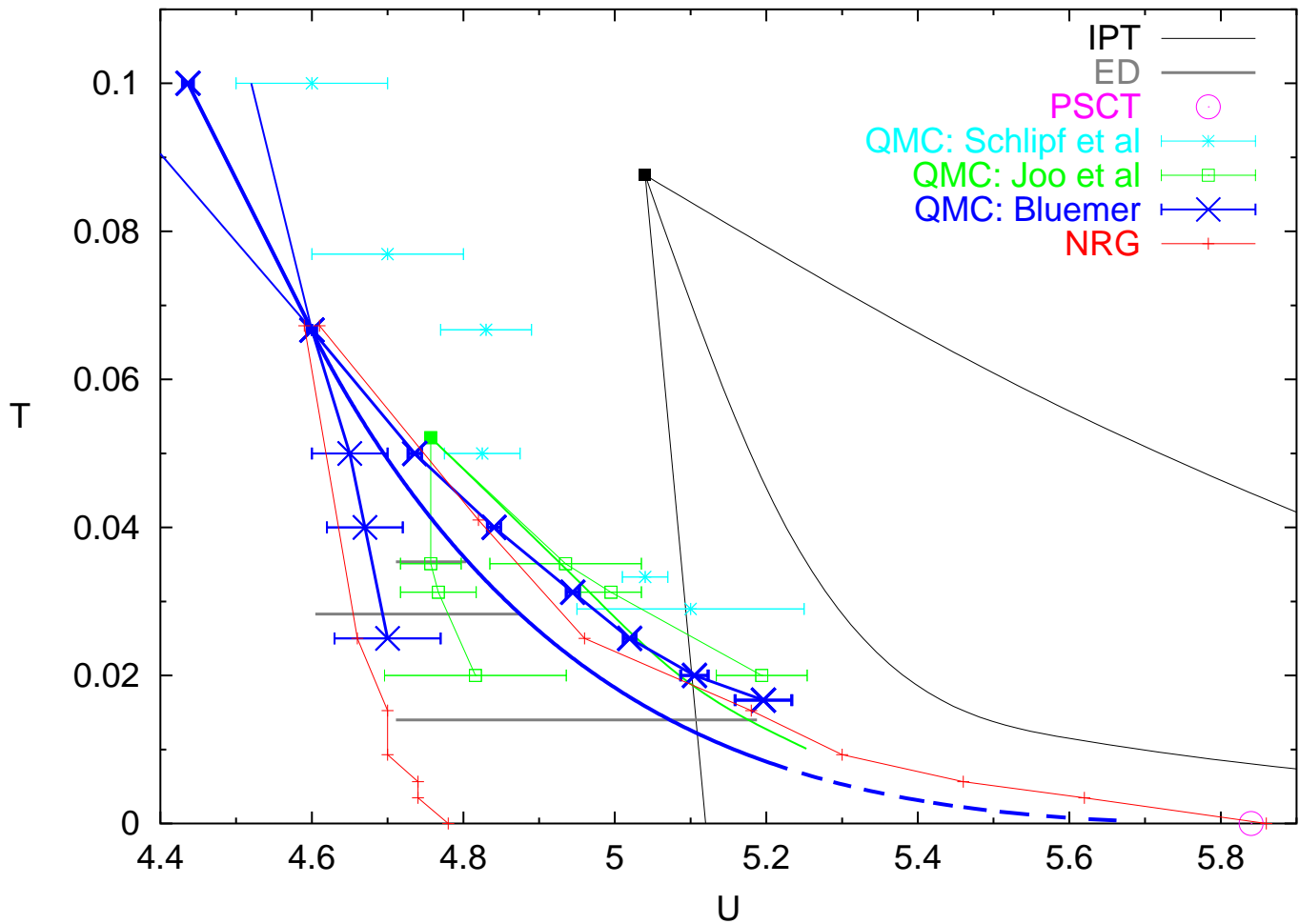
Status of phase diagram in spring 2000



Rozenberg, Chitra and Kotliar (1999)

Moeller et al. (1996)

Full phase diagram: Comparison



Conclusions

- results from fundamentally different methods now converged towards a reliable phase diagram
- coexistence region at low $T \rightarrow$ first order transition
- first controlled computation of $U_c(T)$

Work supported by DFG through SFB484